

Technical Data : AD-011

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ZE650A– Fast Recovery Rectifier

500 - 1500 VRRM; 650 A avg

HIGH POWER Fast Recovery Rectifier

Features:

- . All Diffused Structure
- . High Surge rating
- . Blocking capability up to 1500 volts
- . Soft Reverse Recovery
- . Rugged Ceramic Hermetic Package
- . Pressure Assembled Device



ELECTRICAL CHARACTERISTICS AND RATINGS

Reverse Blocking

Device Type	V _{RRM} (1)	V _{RSM} (1)
ZE650A/500V	500	600
ZE650A/600V	600	720
ZE650A/800V	800	960
ZE650A/1000V	1000	1150
ZE650A/1200V	1200	1300
ZE650A/1400V	1400	1400
ZE650A/1500V	1500	1600

V_{RRM} = Repetitive peak reverse voltage

V_{RSM} = Non repetitive peak reverse voltage (2)

Repetitive peak reverse leakage	I _{RRM}	15 mA 40 mA (3)
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Notes:

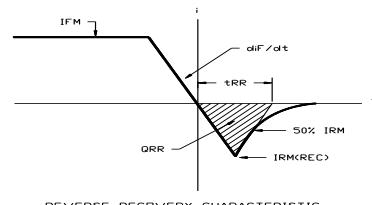
All ratings are specified for T_j=25 °C unless otherwise stated.

(1) All voltage ratings are specified for an applied 50Hz/60Hz sinusoidal waveform over the temperature range -40 to +125 °C.

(2) 10 msec. max. pulse width

(3) Maximum value for T_j = 125 °C.

(4) See parameter definition below :



Conducting - on state

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Average value of on-state current	I _{F(AV)}		650		A	Sinewave, 180° conduction, T _c = 65°C
RMS value of on-state current	I _{FRMS}		1000		A	Nominal value
Peak one cycle surge (non repetitive) current	I _{FSM}		10000		A	8.3 msec (60Hz), sinusoidal wave-shape, 180° conduction, T _j = 125 °C
			9000		A	10.0 msec (50Hz), sinusoidal wave-shape, 180° conduction, T _j = 125 °C
I square t	I ² t		410000		A ² s	8.3 msec and 10.0 msec
Peak on-state voltage	V _{FM}		1.85		V	I _{FM} = 1500 A; Duty cycle ≤ 0.01%
Reverse Recovery Current (4)	I _{RM(REC)}		*		A	I _{FM} = 1000 A; dI _f /dt = 10 A/μs; T _{jmax}
Reverse Recovery Charge (4)	Q _{rr}		120		μC	I _{FM} = 1000 A; dI _f /dt = 10 A/μs; T _{jmax}
Reverse Recovery Time (4)	t _{RR}		2		μs	

* For guaranteed maximum values, contact factory

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Operating temperature	T _j	-40	+125		°C	
Storage temperature	T _{stg}	-40	+125		°C	
Thermal resistance - junction to case	R _{e(j-c)}	0.045 (1)	0.055 (2)		°C/W	Double sided cooled (1) @ 2000 lb.; (2) @ 800 lb.
Thermal resistamce - junction to case	R _{e(j-c)}	0.090 (1)	0.110 (2)		°C/W	Single sided cooled (1) @ 2000 lb.; (2) @ 800 lb.
Thermal resistance - case to sink	R _{e(c-s)}		.030 .060		°C/W	Double sided cooled * Single sided cooled *
Mounting force	P	800 3.6	2500 11.2		lb. kN	
Weight	W			2.5 70	oz. g	

* Mounting surfaces smooth, flat and greased

CASE OUTLINE AND DIMENSIONS

